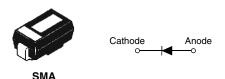


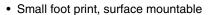
Vishay High Power Products

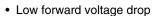
Schottky Rectifier, 2.1 A



PRODUCT SUMMARY			
I _{F(AV)}	2.1 A		
V_{R}	40 V		

FEATURES







- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- · Designed and qualified for industrial level

DESCRIPTION

The 20MQ040NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	2.1	A	
V _{RRM}		40	V	
I _{FSM}	t _p = 5 μs sine	120	A	
V _F	2 Apk, T _J = 125 °C	0.63	V	
T _J	Range	- 55 to 150	°C	

VOLTAGE RATINGS				
PARAMETER SYMBOL		20MQ040NPbF	UNITS	
Maximum DC reverse voltage	V_{R}	40	V	
Maximum working peak reverse voltage	V_{RWM}	40	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T _C = 110 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		2.1	А
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	120	А
See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	30	A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{A}, L = 6 \text{mH}$		3	mJ
Repetitive avalanche current	I _{AR}			1.0	Α

20MQ040NPbF

Vishay High Power Products Schottky Rectifier, 2.1 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} ⁽¹⁾	2 A		0.69	V
		1.5 A	T _J = 25 °C	0.62	
Maximum forward voltage drop		1 A		0.54	
See fig. 1		2 A		0.63	
		1.5 A	T _J = 125 °C	0.56	
		1 A		0.49	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.5	- mA
See fig. 2	IRM (*/	T _J = 125 °C		26	
Threshold voltage	V _{F(TO)}	$T_{J} = T_{J} \text{ maximum} $ 0.36 104		0.36	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	C _T	V _R = 10 V _{DC} , T _J = 25 °C, test signal = 1 MHz		38	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/μs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approximate weight			0.07	g
		0.002	OZ.	
Marking device		Case style SMA (similar D-64)	V2	

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 2.1 A Vishay High Power Products

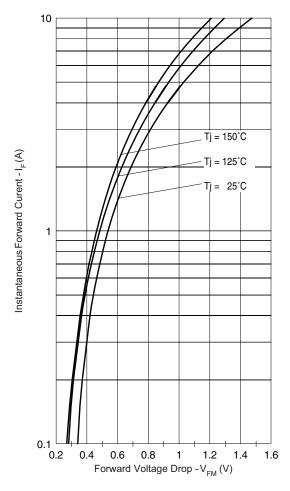


Fig. 1 - Maximum Forward Voltage Drop Characteristics

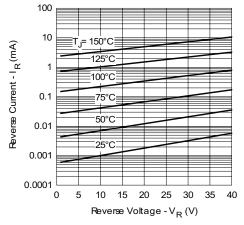


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

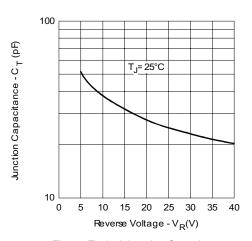


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

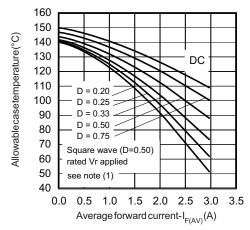


Fig. 4 - Maximum Average Forward Current vs.
Allowable Lead Temperature

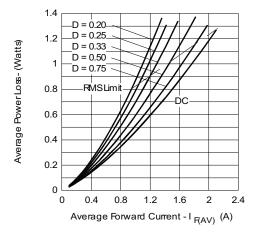


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R

Vishay High Power Products Schottky Rectifier, 2.1 A



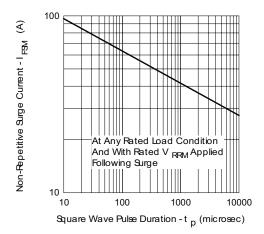
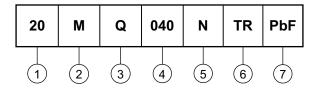


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

ORDERING INFORMATION TABLE

Device code



- 1 Current rating
- 2 M = SMA
- 3 Q = Schottky "Q" series
- 4 Voltage rating (040 = 40 V)
- 5 N = New SMA
- 6 • None = Box (1000 pieces)
 - TR = Tape and reel (7500 pieces)
- | 7 | PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95018			
Part marking information	http://www.vishay.com/doc?95029		
Packaging information	http://www.vishay.com/doc?95034		



Vishay

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